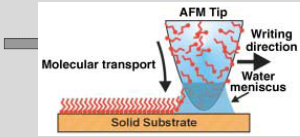
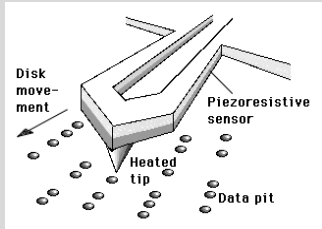
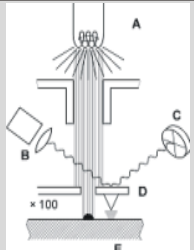
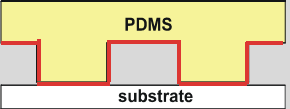
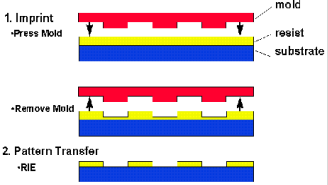
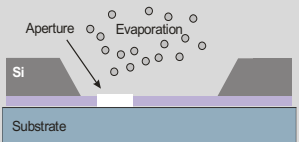
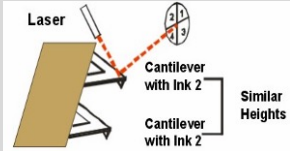
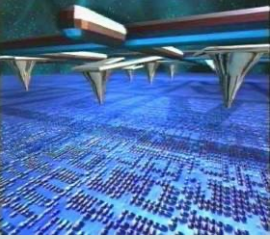
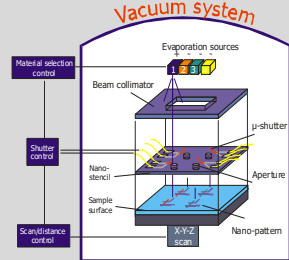


	Molecule Delivery Wet, soft-contact, 100 nm scale	Thermo-mechanical Nano-imprint, embossing, hard contact, 10 nm scale	Local Deposition Stencil, vacuum, no contact 10-100 nm scale
Single & Scanning <i>de novo</i>	 DipPen NADIS 	 Heated AFM 	AFM Nanostencil 
Parallel & Static <i>Replication</i>	Soft-lithography 	NIL 	Membrane Nano-stencil 
Parallel & Scanning <i>Adaptive mass-production</i>	Parallel NADIS 	 Millipede 	Smart Stencil 

Thermal scanning probe lithography (basics)

- Scanning probe lithographies (overview)
- SPM based resist exposure
- SPM based local oxidation
- SPM based liquid dispensing
- SPM based 3D printing (electrochemical)
- Thermal probe lithography
- IBM's millipede project
- Commercial T-SPL tool

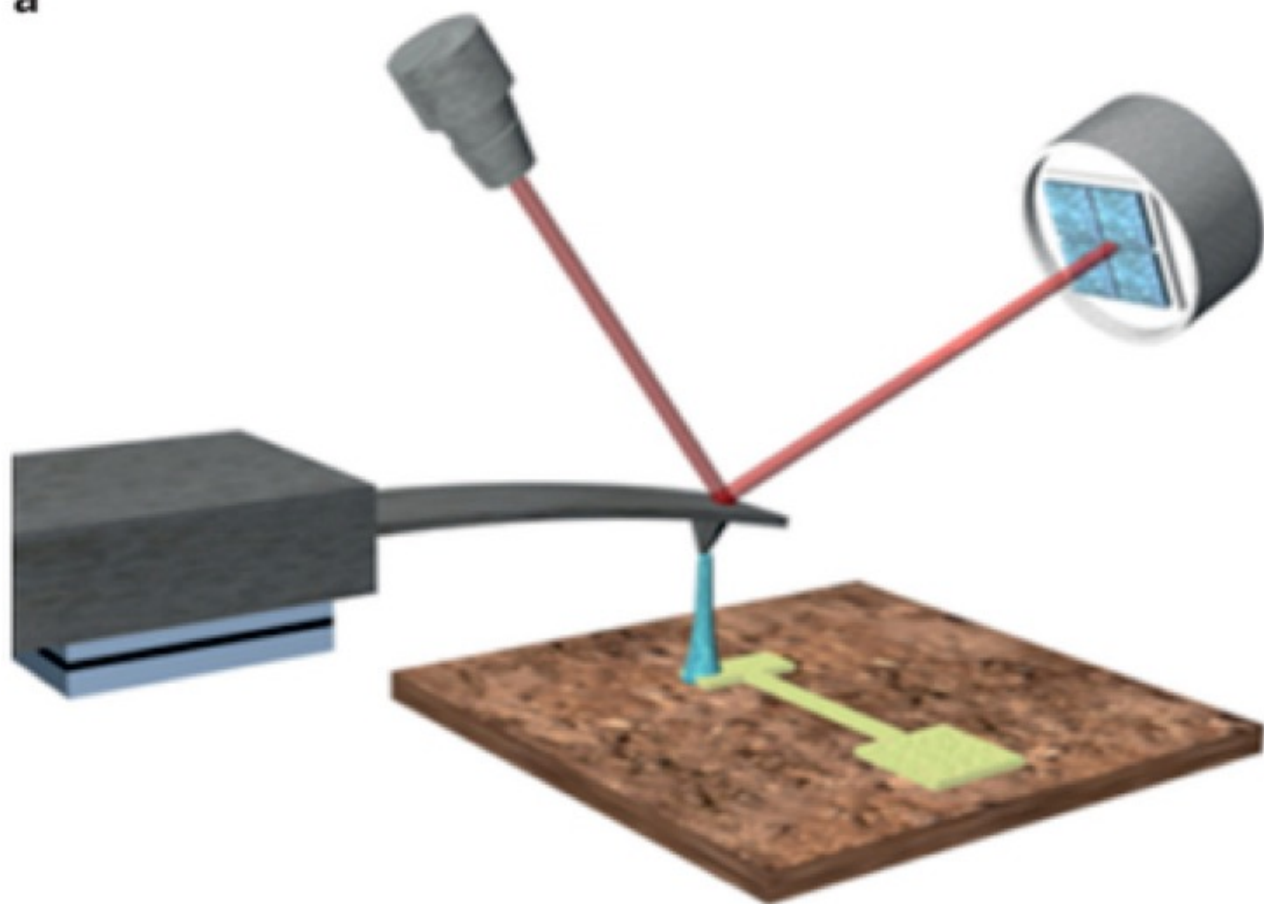
Scanning probe systems

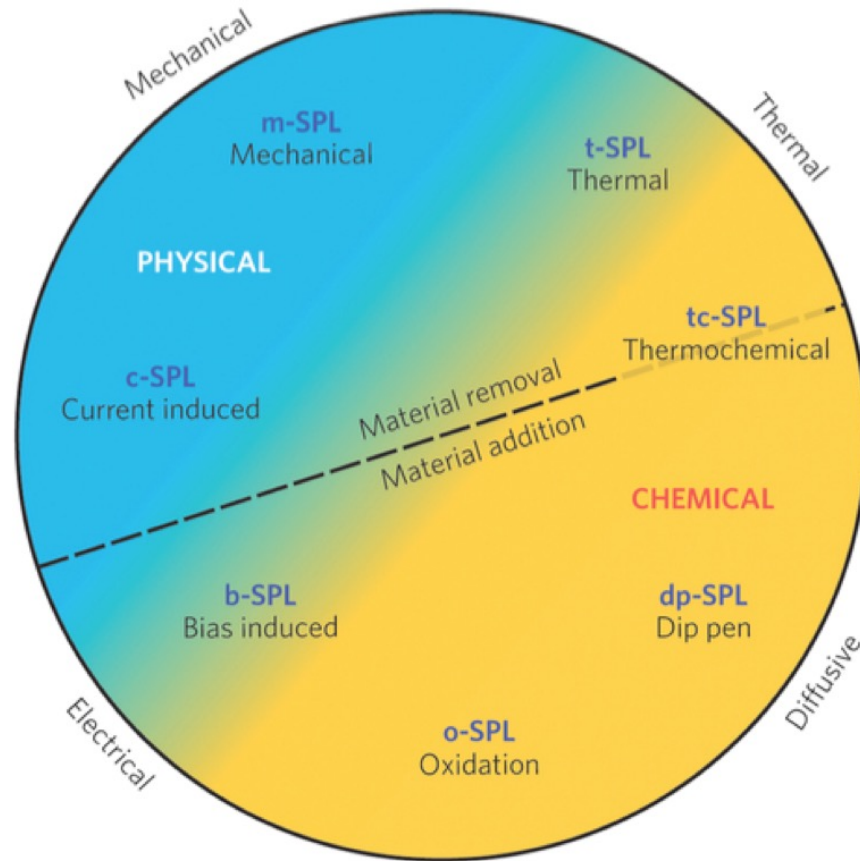
Surface microscopy versus surface modification/patterning

- the **nature** of the interaction determines the sample property that is observed
- the **magnitude** of the interaction determines whether we observe or modify: SPM as a microscope or a tool



a

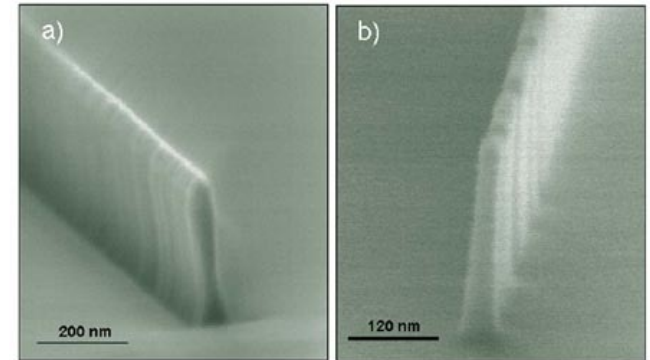
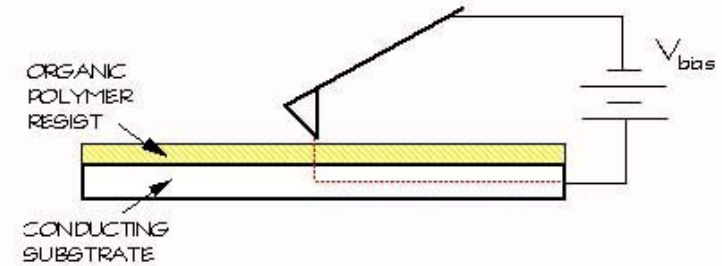




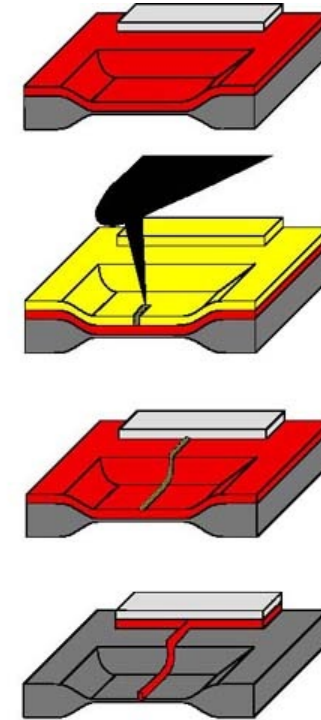
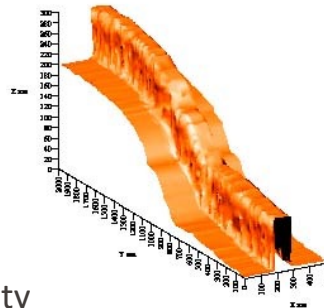
Electron exposure of a resist material, such as an organic polymer or a monolayer resist using field-emission from the tip (induces a chemical changes). This process is in fact very similar to the EBL. Below, the advantages and drawbacks of this technology compared to the EBL are listed.

Advantage: Much cheaper, always in “focus”

Disadvantage: Slower, physical contact between the tip and the surface.



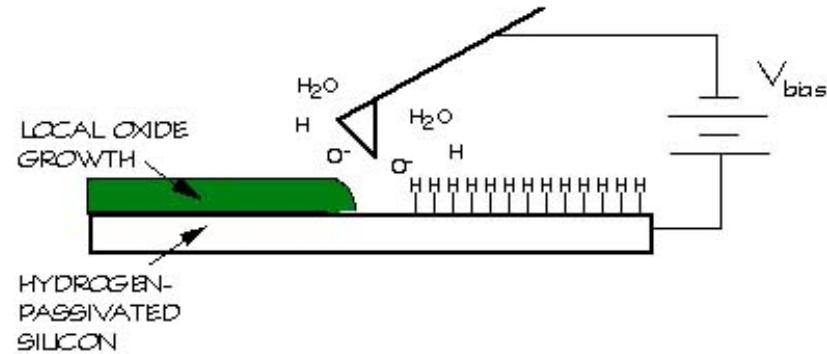
- Exposure of resist (3D capable)
- 100-nm pMOSFET Fabrication Gate Lithography
- Uniform 100-nm Gate Over Topography



■ THERMAL OXIDE	■ POLY	■ SAL-601 RESIST
■ LTO	■ CROSS-LINKED RESIST	

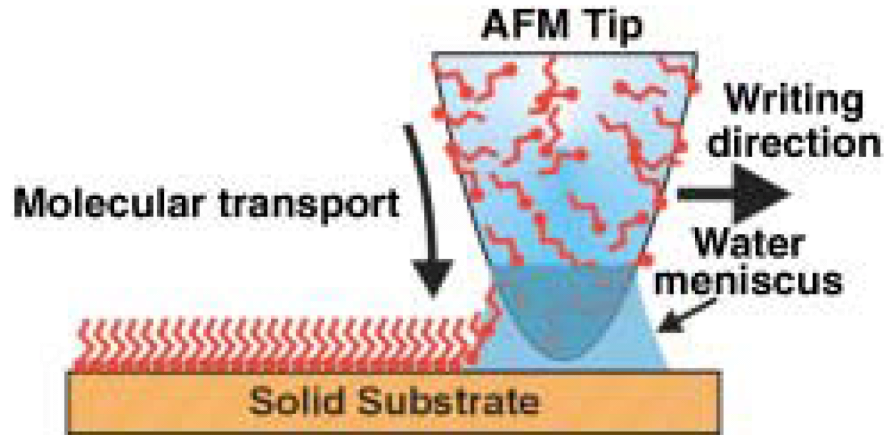
AFM litho

A voltage bias between a sharp probe tip and a sample generates an intense electric field at the tip. The high field can be used to locally oxidize silicon in a process known as electric-field-enhanced oxidation. The high field desorbes the hydrogen passivation on the silicon surface, allowing the exposed silicon to oxidize in air (the oxidation rate is enhanced by the presence of the accelerating field). This local oxidation process is powerful because of its fine resolution (sub-50-nm) and the resistant oxide etch mask that is created.



**Use strong mask
for transfer etch step**

Dip Pen



A tip of an AFM operated in air is “inked” with a chemical of interest and brought into contact with a surface.

The ink molecules flow from the tip onto the surface as with a fountain pen.

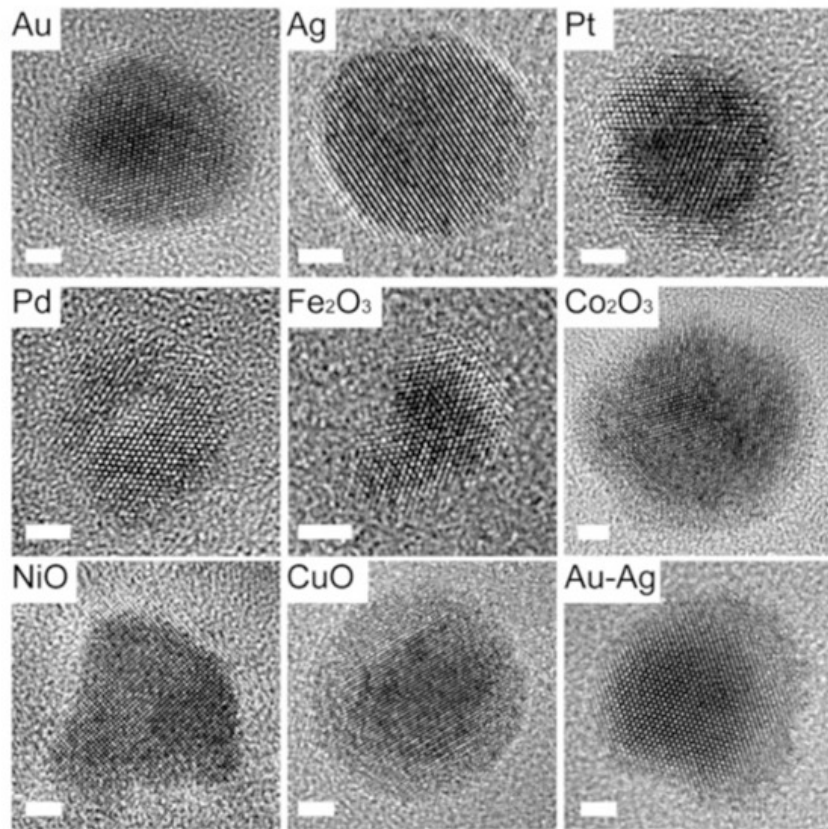
The water meniscus that naturally forms between the tip and the surface enables the diffusion and transport of the molecules.

Possible inks: Polymers, Au, DNA, Antibodies

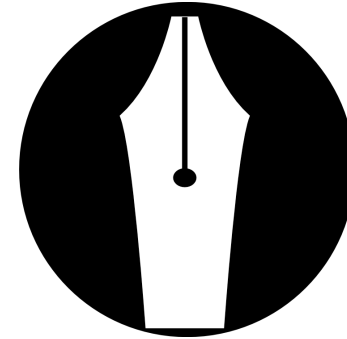
A



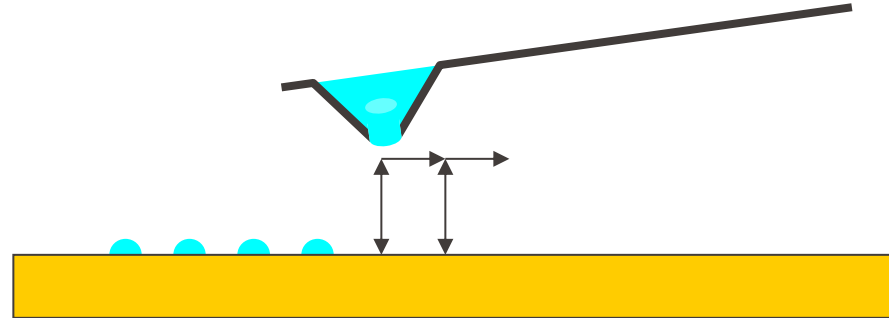
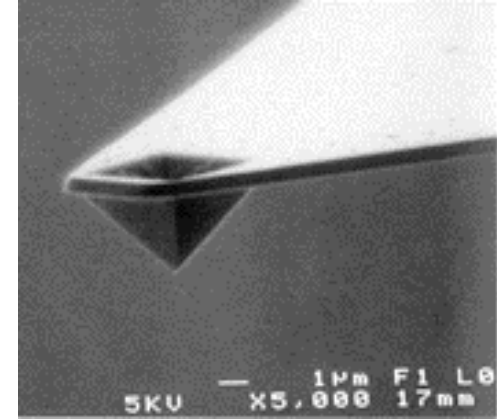
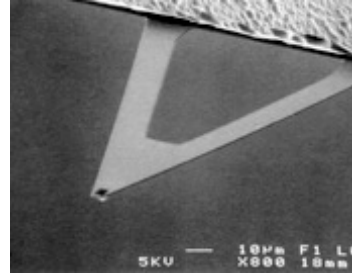
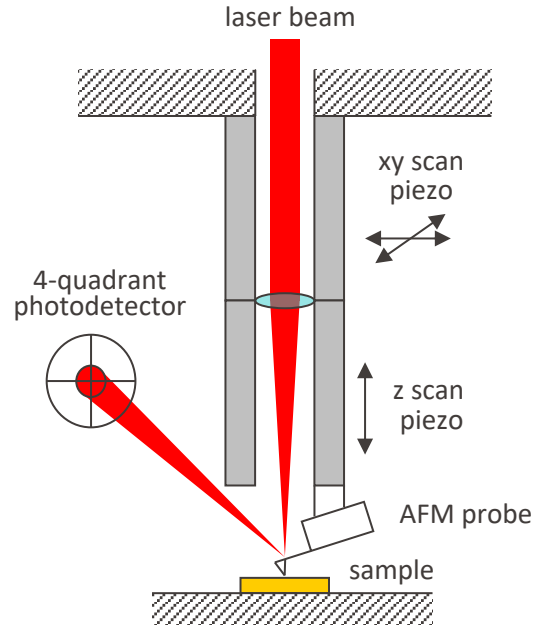
B



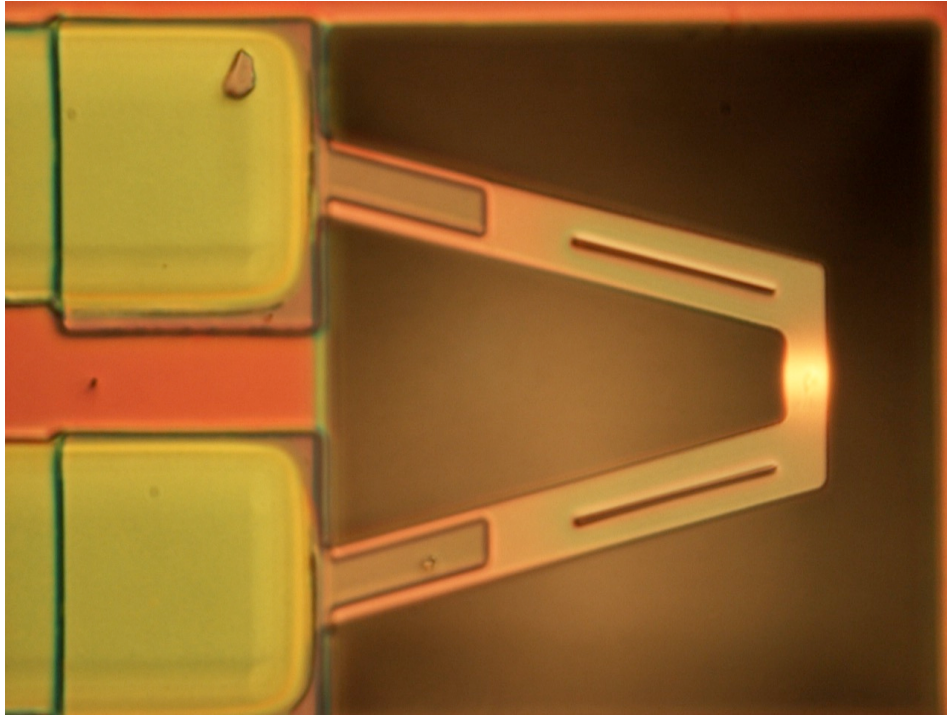
Microfluidics in nanoprobes



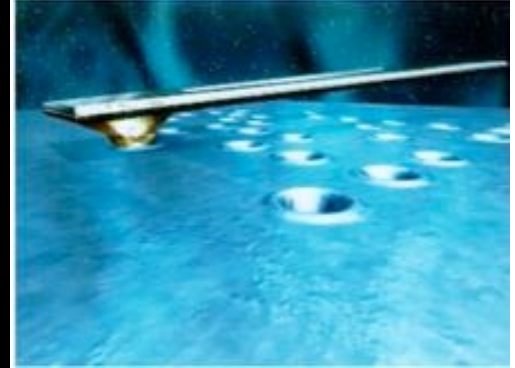
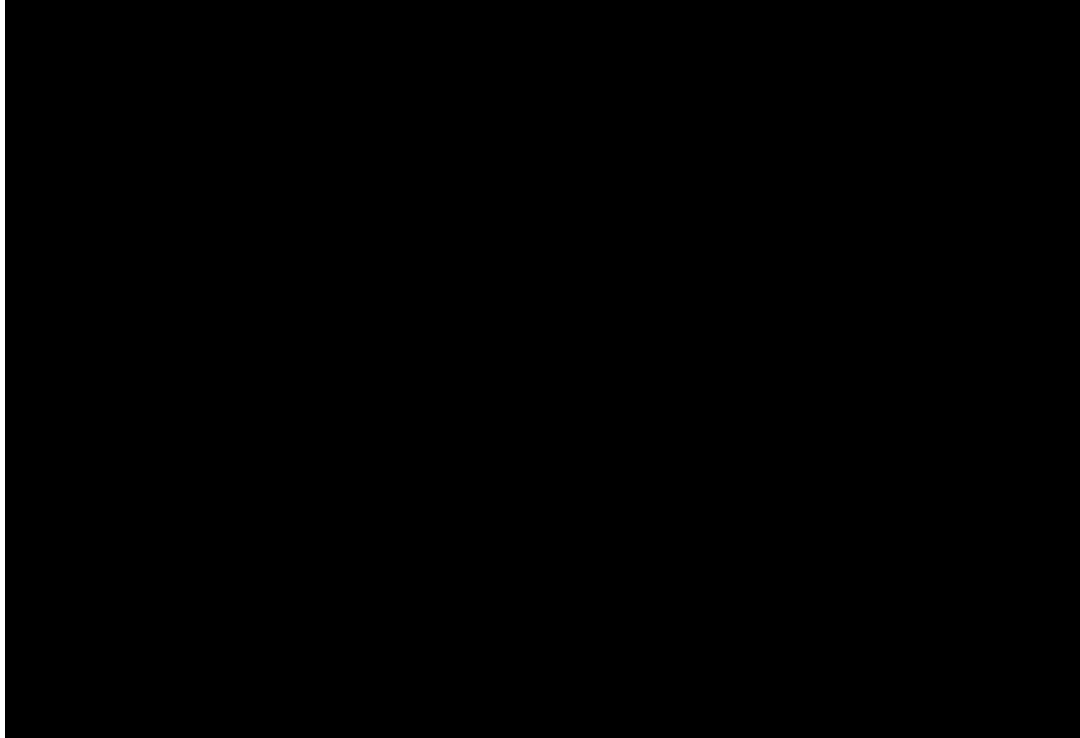
Nanoscale dispenser



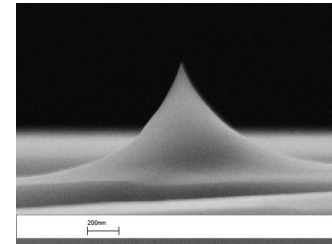
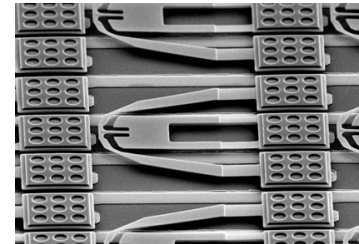
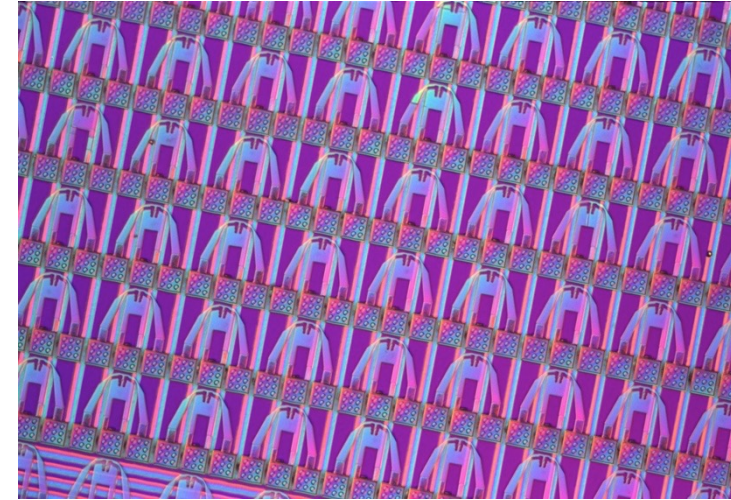
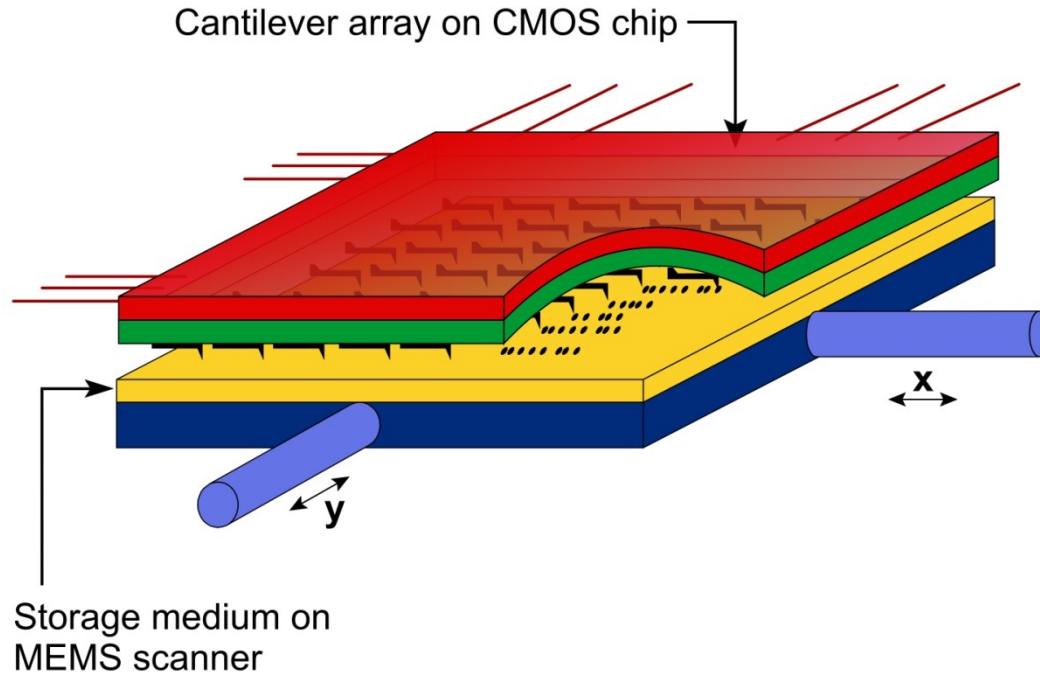
Thermal scanning probe lithography



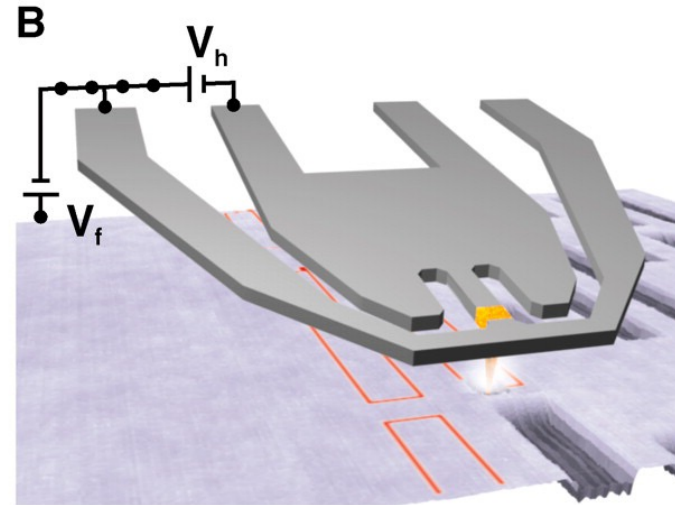
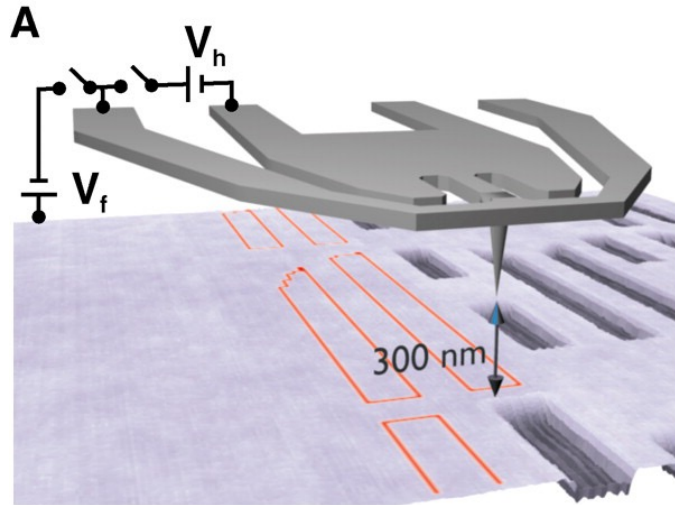
IBM's millipede data storage project



IBM's millipede data storage project

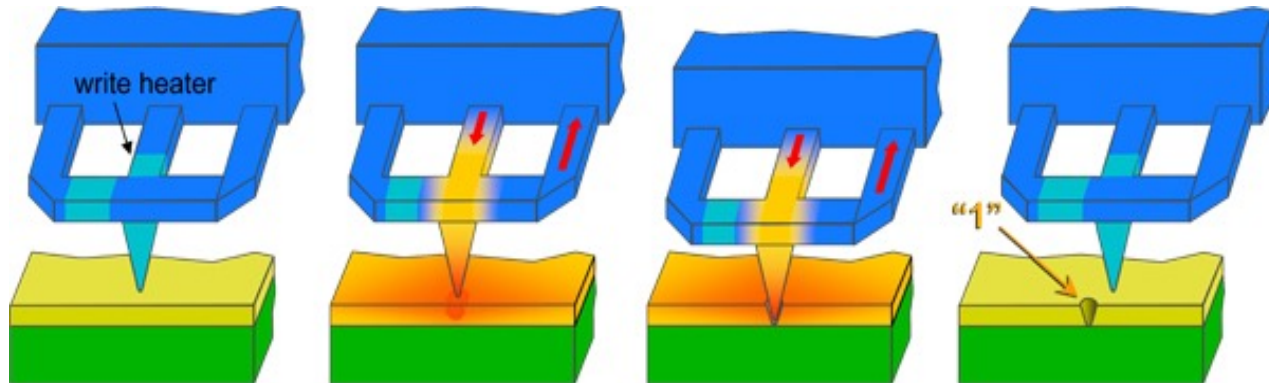


Multifunctional MEMS cantilever



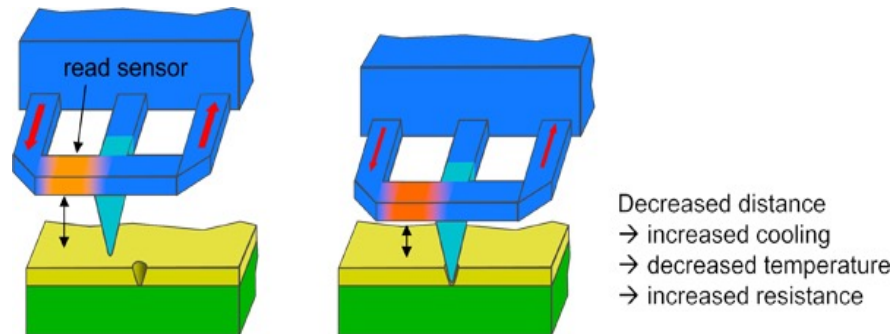
Writing

Thermo-mechanical writing is performed by locally softening the polymer media using the heated tip of a cantilever and simultaneously applying a force to create a nano-scale indentation in the polymer film. The tip is heated by applying a current pulse to a resistive heater integrated into the cantilever, directly behind the tip. During writing, the tip is heated to a temperature above the glass transition temperature of the polymer and forces on the order of a few hundred nanonewtons are applied to the tip for a few microseconds.



Reading

Read-back of the data is performed using a thermo-mechanical sensing technique in which a second resistive heater integrated into the cantilever is heated to a temperature of around 200 °C while the polymer medium is scanned under the tip. The principle of thermal sensing is based on the fact that the rate of cooling of this heater increases as the distance between it and the substrate carrying the polymer medium is reduced. Thus, when the tip moves into an indentation, the distance between the heater and substrate is reduced, resulting in an increase in cooling and hence a decrease in the temperature of the heater. This change in temperature results in an increase in resistance of the heater, which is easily detected by monitoring the current flowing through it.

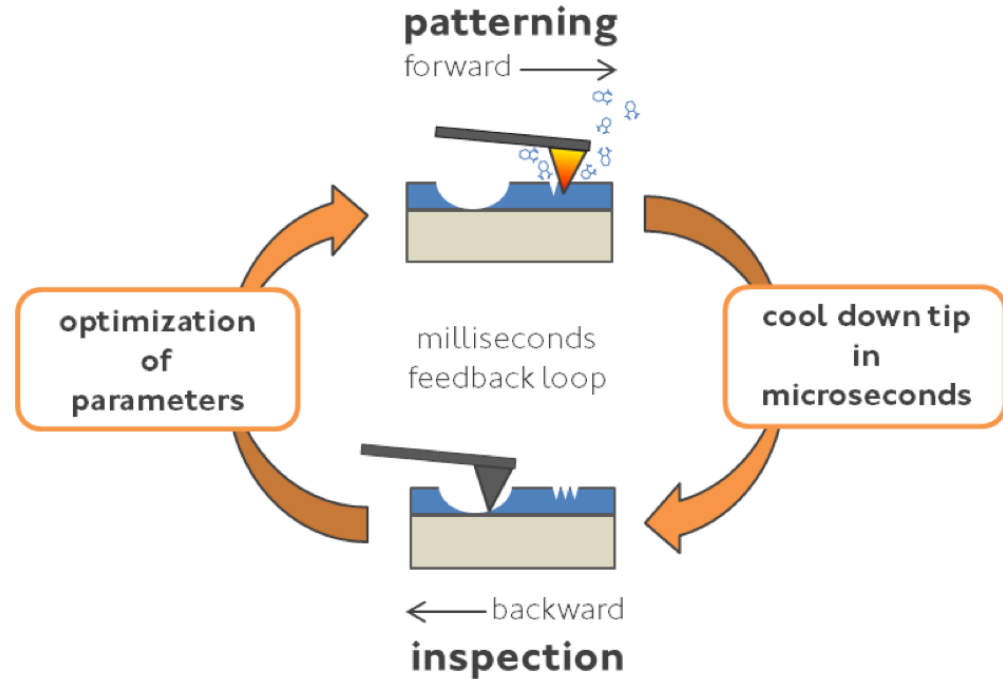
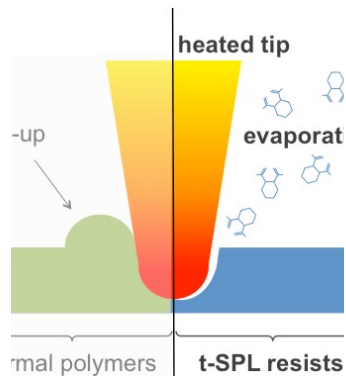


Writing and reading using 1 probe



Closed-loop lithography

- Resist requirement (when heated):
- Not 'flowing' like normal polymer
- Completely removed into vapor phase
- "see what you get"
- In-situ metrology





3D PATTERNING - line # 1
Resist removed by HOT tip ...

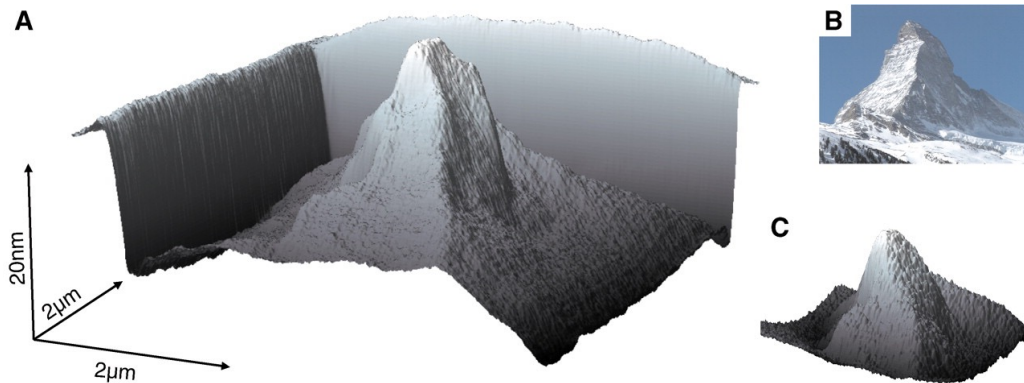
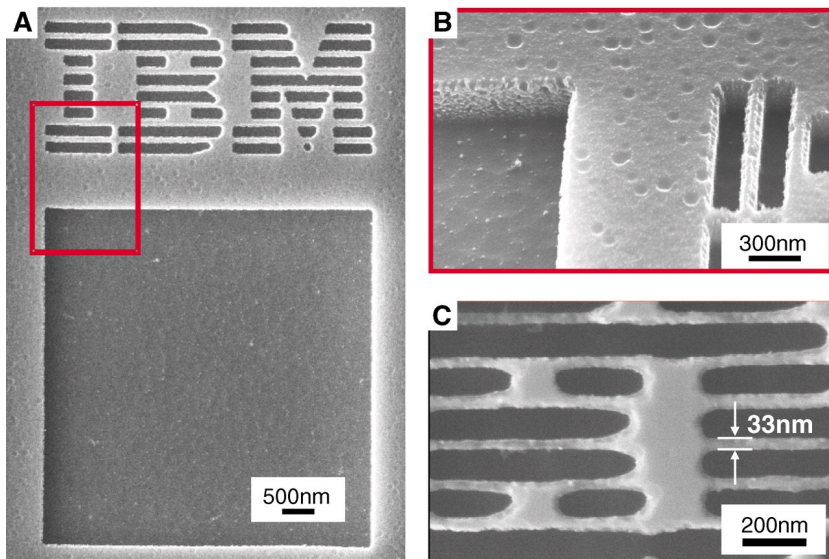
Input Layout



Output AFM image

Line
10
9
8
7
6
5
4
3
2
1

Early T-SPL demonstrations



Thermal scanning probe lithography: take away message

- Nanoscale writing tool
- Various tip-surface interactions
- High resolution (10nm scale)
- Gentle surface contact
- No charged particles damage (with exception of conducting SPM)
- Closed-loop feedback (writing and reading)

- But slow
- Tips are consumables